

Product Summary

| V _{(BR)DSS} | R _{DS(on)TYP} | l _D |
|----------------------|------------------------|----------------|
| 110V | 1.6mΩ@10V | 340A |



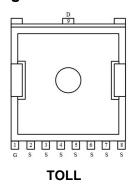
Feature

- Fast Switching
- Low Gate Charge and Rdson
- Advanced Split Gate Trench Technology
- 100% Single Pulse avalanche energy Test

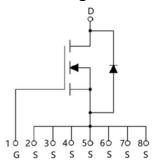
Applications

- PWM Application
- Hard switched and high frequency circuits
- Power Management

Package



Circuit diagram



Marking



SP011N02AGHTO : Product code ** : Week code

Order Information

| Device | Package | Unit/Tape |
|---------------|---------|-----------|
| SP011N02AGHTO | TOLL | 2000 |

110V N-Channel Power MOSFET

Absolute maximum ratings (Ta=25°C unless otherwise noted)

| Parameter | Symbol | Rating | Unit |
|--|------------------|------------|------------|
| Drain-Source Voltage | V _{DS} | 110 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Continuous Drain Current (Tc=25°C) | I _D | 340 | А |
| Continuous Drain Current (Tc=100°C) | ID | 214 | А |
| Pulsed Drain Current | I _{DM} | 1360 | А |
| Single Pulse Avalanche Energy ¹ | E _{AS} | 1956 | mJ |
| Power Dissipation (Tc=25°C) | P _D | 320 | W |
| Thermal Resistance Junction-to-Case | R _{eJC} | 0.39 | °C/W |
| Storage Temperature Range | T _{STG} | -55 to 150 | $^{\circ}$ |
| Operating Junction Temperature Range | TJ | -55 to 150 | °C |

Electrical characteristics (Ta=25°C, unless otherwise noted)

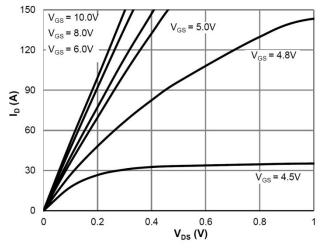
| Characteristics | Symbol | Test Condition | Min | Тур | Max | Unit | |
|--|---------------------|-------------------------------------|-----|-------|------|------|--|
| Static Characteristics | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | VGS=0V , ID=250uA | 110 | 120 | - | V | |
| Drain Cut-Off Current | I _{DSS} | VDS=80V , VGS=0V , TJ=25℃ | - | - | 1 | | |
| Gate Leakage Current | I _{GSS} | VGS=±20V , VDS=0V | - | - | ±100 | μA | |
| Gate Threshold Voltage | V _{GS(th)} | VGS=VDS , ID =250uA | 2 | 3 | 4 | V | |
| Drain-Source ON Resistance | R _{DS(ON)} | VGS=10V , ID=20A | - | 1.6 | 2.1 | mΩ | |
| Dynamic Characteristics | | | | | | | |
| Input Capacitance | Ciss | VDS=50V , VGS=0V , f=1MHz | - | 12220 | - | | |
| Output Capacitance | Coss | | - | 1946 | - | pF | |
| Reverse Transfer Capacitance | Crss | | - | 33 | - | | |
| Total Gate Charge | Qg | | - | 198 | - | nC | |
| Gate-Source Charge | Q _{gs} | VDS=50V , VGS=10V , ID=125A | - | 51 | - | | |
| Gate-Drain Charge | Q _{gd} | | - | 37 | - | | |
| Switching Characteristics | | | | | | | |
| Turn-On Delay Time | t _{d(on)} | VDD=50V, VGS=10V , RG=1.6Ω, ID=125A | - | 25 | - | | |
| Rise Time | t _r | | - | 75 | - | | |
| Turn-Off Delay Time | t _{d(off)} | | - | 89 | - | nS | |
| Fall Time | t _f | | - | 29 | - | | |
| Drain-Source Body Diode Characteristics | | | | | | | |
| Source-Drain Diode Forward Voltage | V _{SD} | I _S = 1A, VGS = 0V | - | - | 1.2 | V | |
| Maximum Body-Diode Continuous Current | Is | | - | - | 340 | Α | |
| Reverse Recovery Time | Trr | | - | 108 | - | nS | |
| Reverse Recovery Charge | Qrr | 15-00A, U/UI-100A/US, 10-20 C | - | 276 | - | nC | |

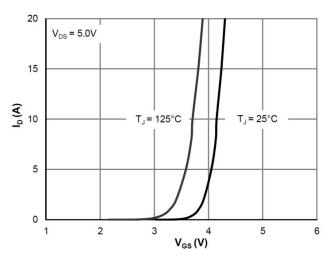
Note:

1. The test condition is VDD=50V,VGS=10V,L=0.5mH,RG=25 Ω



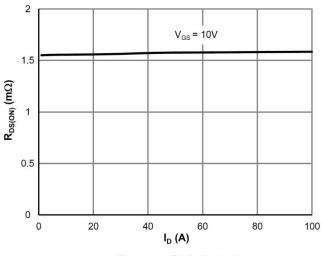
Typical Characteristics

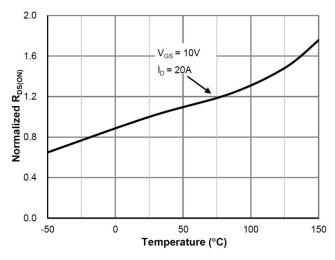




Saturation Characteristics

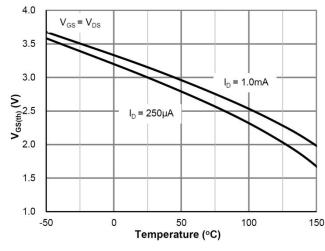


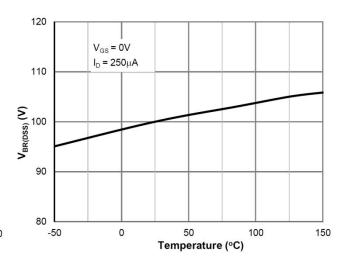




R_{DS(ON)} vs. Drain Current

 $R_{\text{DS(ON)}}$ vs. Junction Temperature

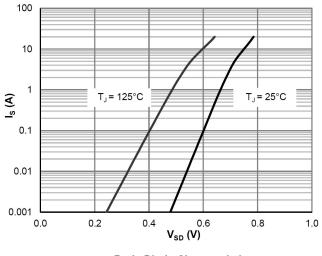


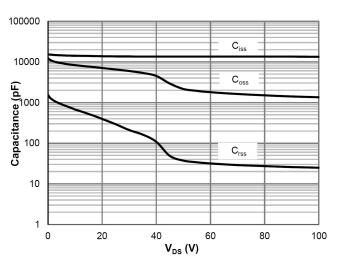


 $V_{\text{GS(th)}}$ vs. Junction Temperature

 $\mathbf{V}_{\mathsf{BR}(\mathsf{DSS})}$ vs. Junction Temperature

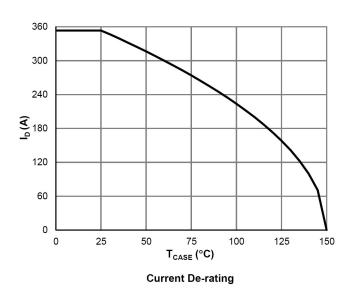


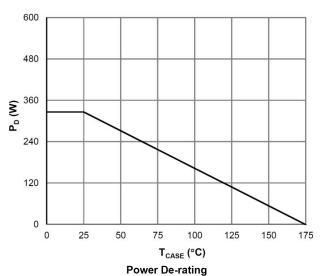


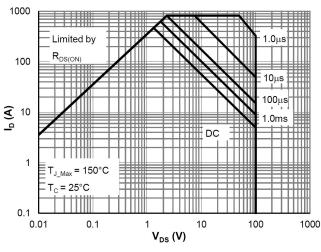


Body-Diode Characteristics

Capacitance Characteristics





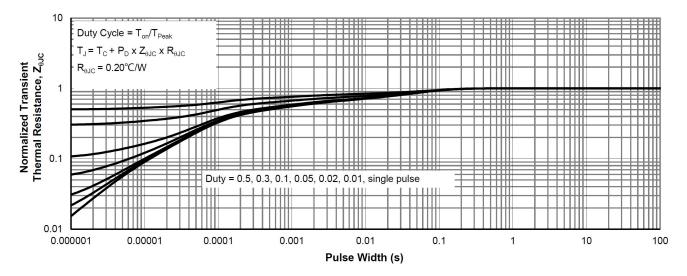


1200 1000 800 800 400 200 0.0001 0.001 0.01 0.1 1 10 100 Pulse Width (s)

Maximum Safe Operating Area

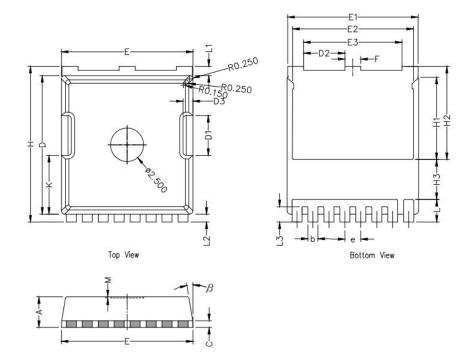
Single Pulse Power Rating, Junction-to-Case

110V N-Channel Power MOSFET



Normalized Maximum Transient Thermal Impedance

TOLL Package Information



| Symbol | Dimensions In Millimeters | | | |
|--------|---------------------------|-----------|-------|--|
| | Min. | Nom. | Max. | |
| А | 2.20 | 2.30 | 2.40 | |
| b | 0.65 | 0.75 | 0.85 | |
| С | | 0.508 REF | | |
| D | 10.25 | 10.40 | 10.55 | |
| D1 | 2.85 | 3.00 | 3.15 | |
| E | 9.75 | 9.90 | 10.05 | |
| E1 | 9.65 | 9.80 | 9.95 | |
| E2 | 8.95 | 9.10 | 9.25 | |
| E3 | 7.25 | 7.40 | 7.55 | |
| е | 1.20 BSC | | | |
| F | 1.05 | 1.20 | 1.35 | |
| Н | 11.55 | 11.70 | 11.85 | |
| H1 | 6.03 | 6.18 | 6.33 | |
| H2 | 6.85 | 7.00 | 7.15 | |
| H3 | 3.00 BSC | | | |
| L | 1.55 | 1.70 | 1.85 | |
| L1 | 0.55 | 0.7 | 0.85 | |
| L2 | 0.45 | 0.6 | 0.75 | |
| M | 0.08 REF. | | | |
| β | 8° | 10° | 12° | |
| K | 4.25 | 4.40 | 4.55 | |